Silicon Schottky Barrier Diode for Various Detector, Mixer

# HITACHI

ADE-208-826 (Z)

Rev. 0 Nov. 1999

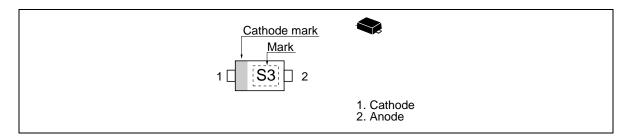
### Features

- Low capacitance. (C = 0.8 pF max)
- Low forward voltage.
- <u>U</u>ltra small <u>F</u>lat <u>Package</u> (UFP) is suitable for high density surface mounting and high speed assembly.

## **Ordering Information**

Type No.	Laser Mark	Package Code
HSC88	S3	UFP

### Outline





## Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Reverse voltage	V <sub>R</sub>	10	V
Average rectified current	I <sub>o</sub>	15	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

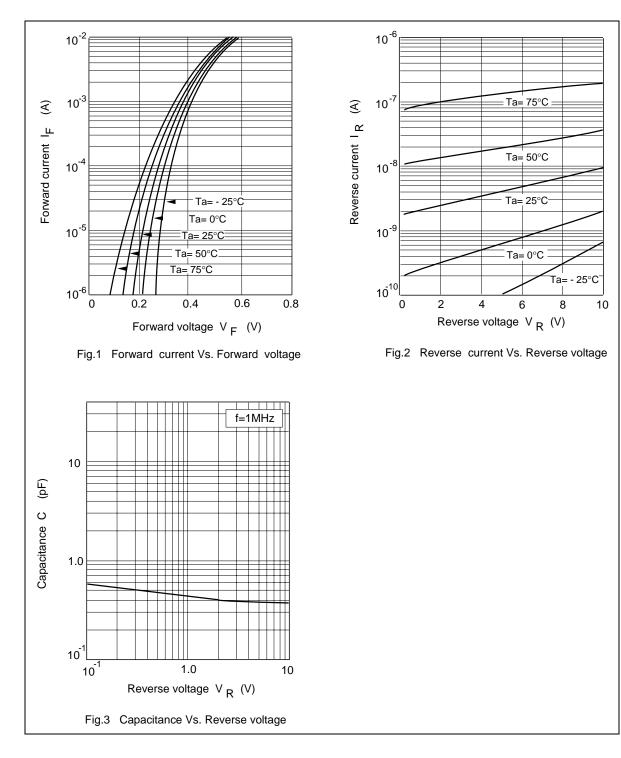
## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

ltem	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V <sub>F1</sub>	350	_	420	mV	I <sub>F</sub> = 1 mA
	V <sub>F2</sub>	500	_	580		$I_{F} = 10 \text{ mA}$
Reverse current	I <sub>R1</sub>	_	_	0.2	μΑ	$V_{R} = 2V$
	I <sub>R2</sub>	—	_	10		$V_{R} = 10V$
Capacitance	С	—	_	0.8	pF	$V_{R} = 0V, f = 1 MHz$
ESD-Capability <sup>*1</sup>	_	30	_	_	V	C = 200pF , Both forward and reverse direction 1 pulse.

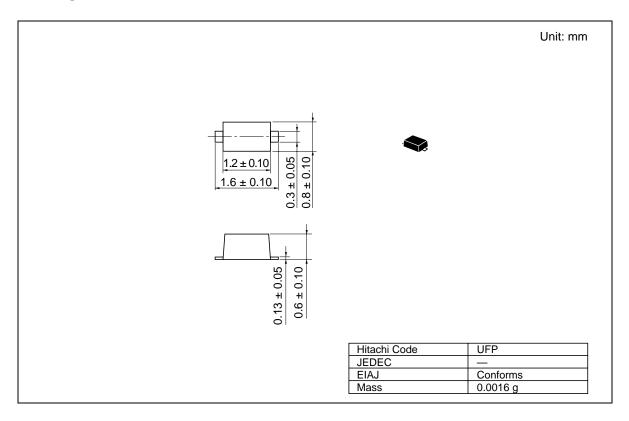
Notes 1. Failure criterion ;  $I_{_{\rm R}} \ge 400 nA$  at  $V_{_{\rm R}}$  =2 V

### Main Characteristic



## **HITACHI**

## **Package Dimensions**



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